

Study of nickel silicide by X- ray diffraction

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Abstract : In order to understand fully the results from X-ray diffraction scattering analysis, it is beneficial to understand the interactions between X-rays and matter. X-ray methods are generally nondestructive, in that sample preparation is not required, and they can provide a very appropriate route to obtain structural information on thin films and multilayers. Analysis can be performed across the whole spectrum of material types from perfect single crystals to amorphous materials. In this work, X-ray diffraction was involved to study the formation of crystalline nickel silicide phases. For this purpose, Ni nanometric thin films were deposited on Si (100). XRD technique has shown that the NiSi silicide is the predominant phase at 350°C. For the annealed samples at 500°C, only NiSi monosilicide is detected. When the annealing temperature increases to 750°C the NiSi₂ disilicide is the main formed phase. The obtained samples were analyzed using scanning electron microscopy (SEM), it shows a surface morphology depending strongly on the substrate orientation.

Keywords : thin film, nickel silicides, X-ray, XRD